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FACSIMILE TRANSMISSION COVER SHEET**Date:** May 10, 2004**To:** United States Patent and Trademark Office
Examiner Luan C. Thai, Art Unit 2827**Fax:** (703) 872-9306**Re:** **Application Serial No.: 10/618,273**
Filing Date: 7/11/2003; Inventor(s): Jeon, et al.
Attorney Docket No.: 0180142**From:** Farjami & Farjami LLP**Number of pages including the cover sheet:** 6**Message:**

Enclosed please find the Amendment and Response to the Office Action dated April 20, 2004.

Thank you.

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Attorney Docket No.: 0180142

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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In re Application of: Jeon, et al.

Serial No.: 10/618,273

Filed: July 11, 2003

For: Method for Forming a Field Effect
Transistor Having a High-K Gate
Dielectric and Related Structure

Art Unit: 2827

Examiner: THAI, LUAN C.

AMENDMENT AND RESPONSE TO OFFICE ACTION

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir/Madam:

This is in response to the Office Action dated April 20, 2004 in the above-referenced patent application. Please enter and consider the following amendments and remarks.